

# Contacting single-molecule magnets with graphene-based electrodes

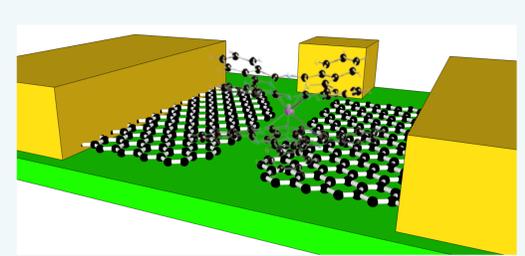
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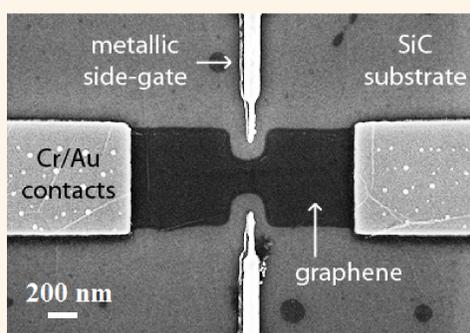
**Abstract.** Graphene is considered a promising material for the fabrication of electrodes for single-molecule devices, since it is stable up to high temperatures and its planar geometry allows for the anchoring of a wide variety of different molecules. Here, we studied three-terminal devices in which a single-molecule magnet (TbPc<sub>2</sub>) is embedded between two nm-spaced few-layer graphene electrodes obtained by electroburning.



## 1. Device fabrication

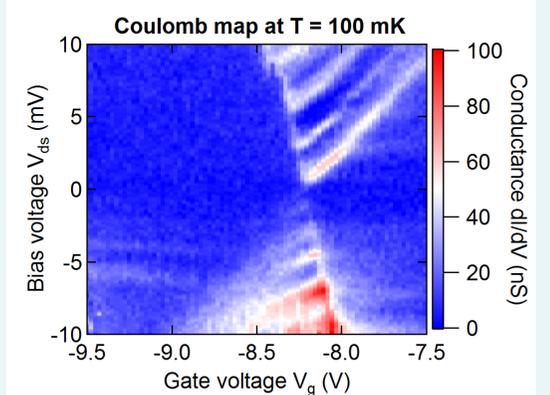
Turbostratic graphene is grown on the C-face of a SiC wafer.

RIE and EBL are used to pattern graphene in the desired geometry and to fabricate the electrical contacts<sup>1</sup>.



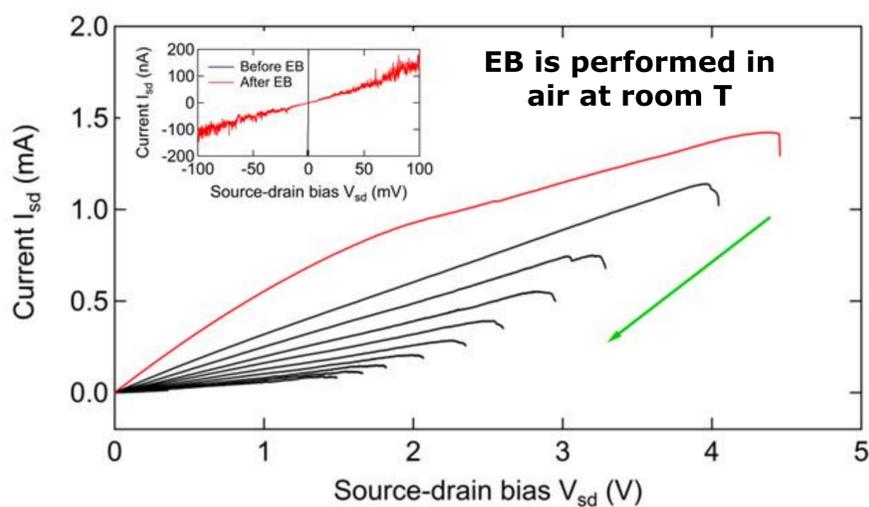
## 3a. TbPc<sub>2</sub> molecules between graphene electrodes: transport properties

At low T (~100 mK) diamond-like features appear in the stability diagrams: charge transport is in the **Coulomb blockade regime**.



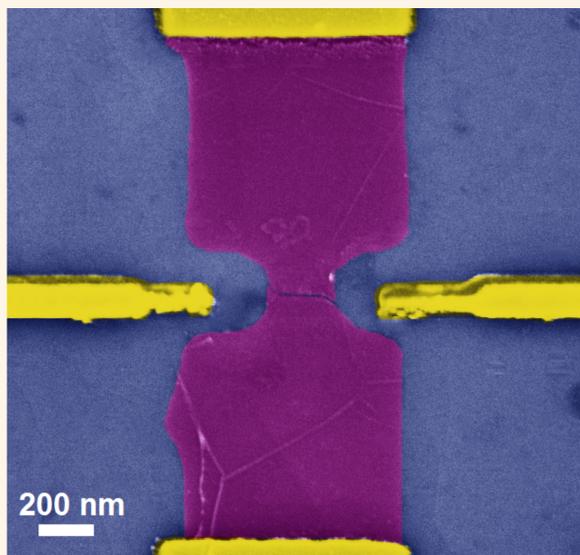
## 2. Electroburning

The presence of a fast **feedback loop**<sup>2</sup> avoids the abrupt breaking of the graphene junction.



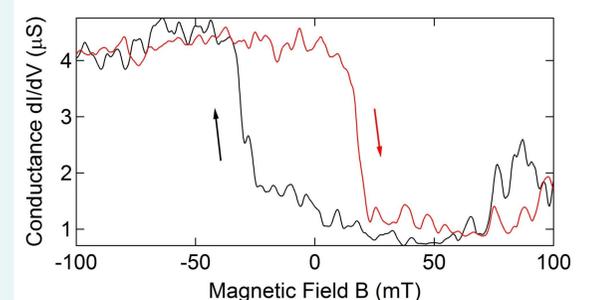
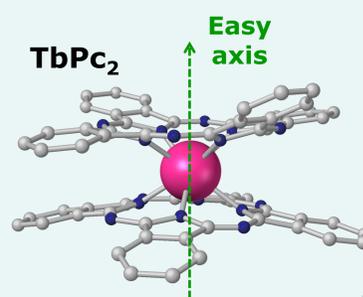
Nearly 90% of the junctions can be controllably led to a low-bias resistance between 100 kΩ and 3 MΩ.

Subsequent cool down at low T completes the opening of the nanogaps.

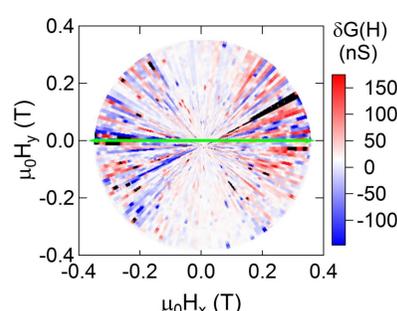


## 3b. TbPc<sub>2</sub> molecules between graphene electrodes: spin properties

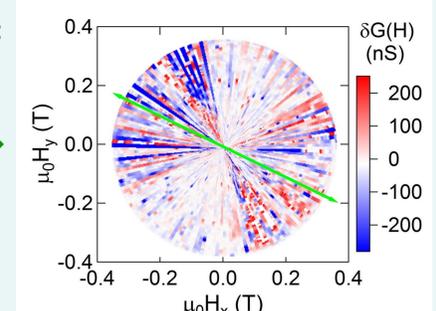
Abrupt jumps in the magneto-conductance are likely due to the switching of the TbPc<sub>2</sub> electronic spin.



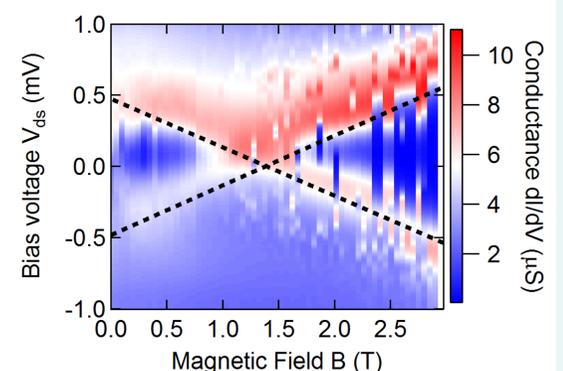
### Uniaxial anisotropy



45° tilt of the sample



A strong **antiferromagnetic coupling** to the Tb<sup>3+</sup> electronic spin could explain the splitting of the spin 1/2 Kondo peak at zero magnetic field.



## References:

- [1] A. Candini et al., Beilstein J. Nanotechnol. **6**, 711 (2015)  
 [2] F. Prins et al., Nano Lett. **11**, 4607 (2011)